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INFORMATION DISCLOSURE STATEMENT BY APPLICANT	Applicant K. Shepard		
(Use several sheets if necessary)	Filing Date June 9, 2000	Group 2858	

U.S. PATENT DOCUMENTS

*Exam. Init.	Document No.	Date	Name	Class	Subclass	Filing Date if Appro.		
	FORE	IGN PATENT	DOCUMENTS	•	,			
	Document No.	Date	Country	Class	Subclass	Translation Yes No		
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^{*} Examiner: Initial citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.